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IS : 7962 - 1975

Indian Standard

METHODS OF MEASUREMENT FOR
PIEZOELECTRIC VIBRATORS OPERATING
OVER THE FREQUENCY RANGE UP TO 30 MHz

UDC 621.372.412 : 621.373.5 : 621.317.34



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MANAK BHAVAN, 9 BAHADUR SHAH ZAFAR MARG
NEW DELHI 110002

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August 1976

Indian Standard

METHODS OF MEASUREMENT FOR PIEZOELECTRIC VIBRATORS OPERATING OVER THE FREQUENCY RANGE UP TO 30 MHz

Piezoelectric Devices for Frequency Control and Selection Sectional
Committee, ETDC 51

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Indian Standard

METHODS OF MEASUREMENT FOR PIEZOELECTRIC VIBRATORS OPERATING OVER THE FREQUENCY RANGE UP TO 30 MHz

0. FOREWORD

0.1 This Indian Standard was adopted by the Indian Standards Institution on 24 December 1975, after the draft finalized by the Piezoelectric Devices for Frequency Control and Selection Sectional Committee had been approved by the Electrotechnical Division Council.

0.2 The object of this standard is to provide methods of measurement for piezoelectric vibrators operating over the frequency range up to 30 MHz.

0.2.1 The transmission method described in this standard is suitable for frequencies up to 30 MHz for the commonly encountered ranges of the capacitance ratio r and the figure of merit M , provided that errors due to instrumentation are taken into account. The equations presented in this standard have been formulated to correct these errors.

0.3 In preparing this standard assistance has been derived from the IEC Pub 302-1969 'Standard definitions and methods of measurement for piezoelectric vibrators operating over the frequency range up to 30 MHz' issued by the International Electrotechnical Commission.

0.4 In reporting the result of a test or analysis made in accordance with this standard, if the final value, observed or calculated, is to be rounded off, it shall be done in accordance with IS : 2-1960.*

1. SCOPE

1.1 This standard describes the methods of measurement for piezoelectric vibrators operating over the frequency range up to 30 MHz.

2. TERMINOLOGY

2.0 For the purpose of this standard, the definitions of terms given in IS : 1885 (Part V)-1965† and IS : 1885 (Part XXXIII)-1972‡ shall apply.

3. PIEZOELECTRIC VIBRATOR

3.1 General — A vibrator consists of an element usually in the form of a

*Rules for rounding off numerical values (*revised*).

†Electrotechnical vocabulary: Part V Quartz crystals.

‡Electrotechnical vocabulary: Part XXXIII Piezoelectric filters.

plate, bar or ring cut from a piezoelectric material and has electrodes attached to or supported near the element to excite one of its resonance frequencies.

3.2 Equivalent Electric Circuit of a Piezoelectric Vibrator — The electrical behaviour of a lightly damped mechanical vibrating system which is excited piezoelectrically through electrodes forming a two-terminal network can be represented in the vicinity of any mechanical resonance by an equivalent electric circuit (see Fig. 1) which consists of a capacitance C_1 , inductance L_1 and resistance R_1 in series, shunted by the parallel capacitance C_0 . The parameters are independent of frequency for isolated modes of motion.

NOTE — Generally, the mode in question is sufficiently isolated from other modes to permit this assumption. When this is not true, the equations and measuring methods outlined herein do not apply.

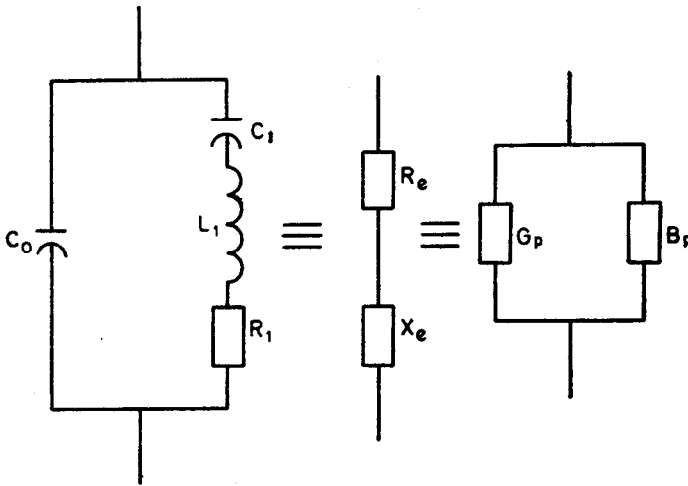


FIG. 1 EQUIVALENT ELECTRIC CIRCUIT OF A PIEZOELECTRIC VIBRATOR
NEAR A RESONANCE

3.3 Parameters of Piezoelectric Vibrators

3.3.1 The fundamental parameters C_1 , L_1 , R_1 and C_0 define the equivalent electric circuit shown in Fig. 1 and all other parameters may be derived from them. At a given frequency the parameters of the equivalent electric circuit generally approach constant values as the amplitude of vibration approaches zero. The amplitude which can be tolerated before the parameters are appreciably affected varies widely among vibrators of

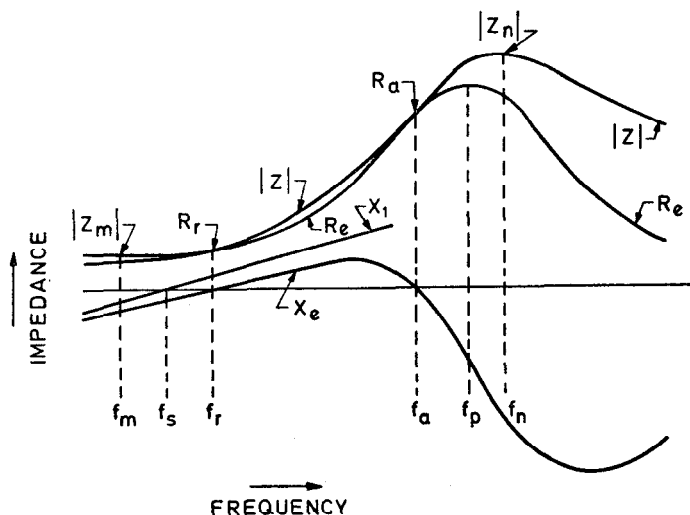
various types and can only be determined by experiment.

3.3.2 The basic equation for the impedance \bar{z} or admittance γ of the equivalent electric circuit of the piezoelectric vibrator is given below:

$$\bar{z} = \frac{1}{\gamma} = \frac{j}{\omega C_0} \cdot \frac{\Omega - j\delta}{1 - \Omega + j\delta} \quad \dots (1)$$

3.3.3 Equation (1) describes the relationship between the various parameters of the piezoelectric vibrator. The symbols used in equation (1) and the other essential parameters are given in Table 1. The characteristic frequencies of equation (1) are defined in Table 2.

3.3.4 The magnitude of the impedance of the equivalent electric network ($|\bar{z}|$), its resistive component (R_e), its reactive component (X_e) and the reactance X_1 of the C_1, L_1, R_1 branch are plotted as functions of frequency in Fig. 2 for the purpose of defining the different characteristic frequencies. $|\bar{z}_m|$ and $|\bar{z}_n|$ denote minimum and maximum impedance respectively. R_r and R_a are the impedances at zero phase angle. These curves, however, have only qualitative character and do not represent a particular piezoelectric vibrator.



NOTE 1— $|\bar{z}_m|$ and $|\bar{z}_n|$ denote minimum and maximum impedance. R_r and R_a are the impedances at zero phase angle.

NOTE 2—The identification of different frequencies are given in Table 1.

FIG. 2 IMPEDANCE $|\bar{z}|$, RESISTANCE R_e , REACTANCE X_e AND SERIES ARM REACTANCE X_1 OF A PIEZOELECTRIC VIBRATOR AS A FUNCTION OF FREQUENCY

TABLE 1 LIST OF SYMBOLS USED FOR THE EQUIVALENT ELECTRIC CIRCUIT OF A PIEZOELECTRIC VIBRATOR

(Clauses 3.3.3, 4.1.2, and Fig. 2 and 3)

SYMBOL	MEANING	SI UNIT
B_p	Equivalent parallel susceptance of vibrator	siemen
C_0	Shunt (parallel) capacitance in the equivalent electric circuit	farad
C_1	Motional capacitance in the equivalent electric circuit	farad
f	Frequency	hertz
f_a	Antiresonance frequency, zero susceptance	hertz
f_m	Frequency of maximum admittance (minimum impedance)	hertz
f_n	Frequency of minimum admittance (maximum impedance)	hertz
f_p	Parallel resonance frequency (lossless) = $\frac{1}{2\pi\sqrt{L_1\frac{C_1C_0}{C_1+C_0}}}$	hertz
f_r	Resonance frequency, zero susceptance	hertz
f_s	Motional (series) resonance frequency = $\frac{1}{2\pi\sqrt{L_1C_1}}$	hertz
G_p	Equivalent parallel conductance of vibrator	siemen
L_1	Motional inductance in the equivalent electric circuit	henry
M	Figure of merit of a vibrator: $M = \frac{Q}{r} = \frac{1}{\omega_s C_0 R_1}$	dimensionless
Q	Quality factor: $Q = \frac{\omega_s L_1}{R_1} = \frac{1}{\omega_s C_1 R_1} = r M$	dimensionless
r	Capacitance ratio: $r = \frac{C_0}{C_1}$	dimensionless
R_a	Impedance at zero phase angle near antiresonance	ohm
R_e	Equivalent series resistance of vibrator	ohm
R_r	Impedance at f_r zero phase angle	ohm
R_1	Motional resistance in the equivalent electric circuit	ohm
X_e	Equivalent series reactance of vibrator	ohm
X_0	Reactance of shunt (parallel) capacitance at series resonance: $X_0 = \frac{1}{\omega_s C_0}$	ohm

(Continued)

TABLE 1 LIST OF SYMBOLS USED FOR THE EQUIVALENT ELECTRIC CIRCUIT OF A PIEZOELECTRIC VIBRATOR — Contd

SYMBOL	MEANING	SI UNIT
X_1	Reactance of motional series arm of vibrator: $X_1 = \omega L_1 - \frac{1}{\omega C_1}$	ohm
γ	Admittance of vibrator: $\gamma = G_p + jB_p = \frac{1}{Z}$	siemen
γ_m	Maximum admittance of vibrator	siemen
γ_n	Minimum admittance of vibrator	siemen
Z	Impedance of vibrator: $Z = R_e + jX_e$	ohm
Z_m	Minimum impedance of vibrator	ohm
Z_n	Maximum impedance of vibrator	ohm
$ Z $	Absolute value of impedance of vibrator: $Z = \sqrt{R_e^2 + X_e^2}$	ohm
$ Z_m $	Absolute value of impedance at f_m (minimum impedance)	ohm
$ Z_n $	Absolute value of impedance at f_n (maximum impedance)	ohm
δ	Normalized damping factor: $\delta = \omega C_0 R_1$	dimensionless
Ω	Normalized frequency factor: $\Omega = \frac{f^2 - f_s^2}{f_r^2 - f_s^2}$	dimensionless
ω	Circular (angular) frequency: $\omega = 2 \pi f$	radian/second
ω_s	Circular frequency at motional resonance: $\omega_s = 2 \pi f_s$	radian/second

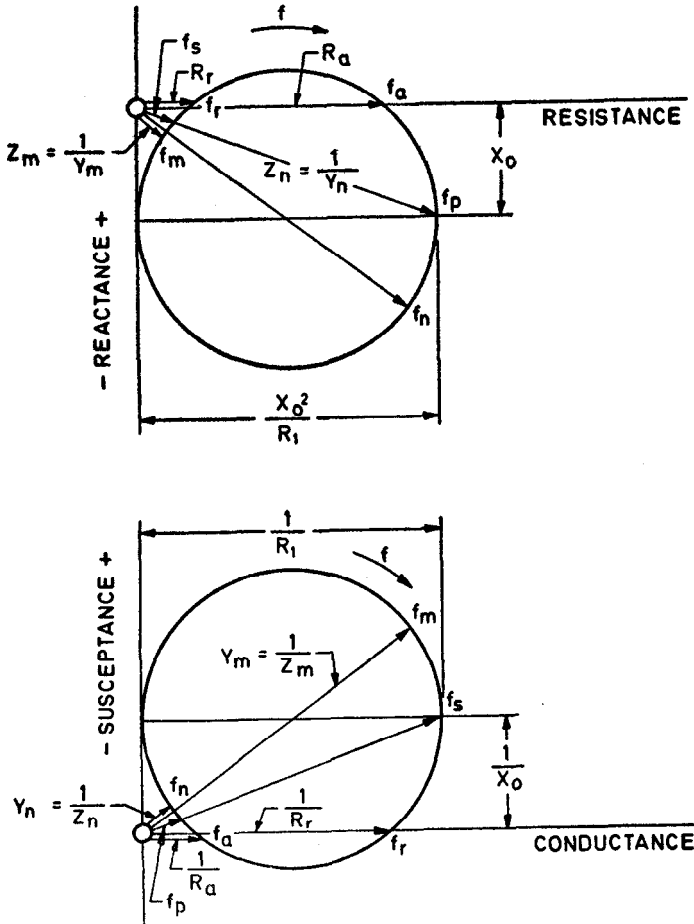
3.3.5 For further clarification, the impedance and admittance circles of a piezoelectric vibrator are reproduced in Fig. 3. However, the circle representation of the impedance or admittance of a piezoelectric vibrator is valid only if the circle diameter of the admittance diagram is large compared with the change of $2 \pi f C_0$ in the resonance range or if $r \ll Q^2$, which is fulfilled in most vibrators. If the latter conditions are not fulfilled, the admittance curve shows a cissoidal character. In this standard, it is assumed that the impedance (or admittance) of the vibrator can be represented by a circle diagram. Table 3 gives data for Q , r and Q^2/r for various types of vibrators indicating that this assumption is valid for all practical cases.

3.3.6 It is necessary to make approximations in deriving practical equations for general use. It is the error of these approximations, in addition

to the errors of instrumentation, that govern the overall accuracy of the experimentally derived parameters.

3.3.7 As a first approximation sufficient for many practical purposes, the following assumptions can be made:

$$f_m = f_r = f_s \text{ and } f_a = f_n = f_p$$



NOTE — The symbols conform with those in Table 1 and Fig. 2.

FIG. 3 IMPEDANCE AND ADMITTANCE DIAGRAM OF A PIEZOELECTRIC VIBRATOR

3.3.8 More exact relations between the characteristic frequencies f_m , f_r , f_a , f_p , f_n and the series resonance frequency f_s of a vibrator valid for the figure of merit $M > 10$ and the capacitance ratio $r > 10$ are shown in Table 4. These relationships have been derived by various authors under the assumption that $M \gg 1$.

3.3.9 The separation between parallel and series resonance frequencies is given below:

$$\frac{f_p^2 - f_s^2}{f_s^2} = \frac{C_1}{C_0} = \frac{1}{r} \quad \dots (2)$$

The approximation

$$\begin{aligned} \frac{f_p - f_s}{f_s} &= \sqrt{1 + r^{-1}} - 1 \\ &= \frac{1}{2r} \left(1 - \frac{1}{4r} + \dots \right) \approx \frac{1}{2r} \\ &= \frac{1}{2} \frac{C_1}{C_0} \quad \dots (3) \end{aligned}$$

can be used for larger value of r (for example, when r is greater than 25 the error is less than 1 percent).

4. TRANSMISSION CIRCUIT METHOD OF MEASURING THE PARAMETERS OF THE EQUIVALENT ELECTRIC CIRCUIT

4.1 General

4.1.1 This method is based on measuring the frequency and impedance at maximum transmission (maximum transfer impedance) of a π -network containing the equivalent electric circuit of the vibrator under test in the series branch, as shown in Fig. 4. The frequency f_{mT} at maximum transmission (maximum output voltage) is measured both with and without the capacitance C_L in series with the vibrator. From these measurements, the motional resonance frequency f_s and the motional capacitance C_1 of the vibrator can be determined. The value for R_1 can be obtained by substitution of a resistance R_{st} in place of the vibrator to obtain the same output voltage.

4.1.2 All symbols describing the transmission method are given in Tables 1 and 5.

4.1.3 Table 6 contains, in the second column, a compilation of the expressions for R_1 and, in the third column, the exact deviation of the frequency at minimum transfer admittance f_{mT} from the motional resonance frequency f_s of the vibrator. The exact solutions shown in Table 6 can be simplified if the assumptions mentioned in the left-hand column of the table are made. When the parallel inductance L_0 is not used, then $b = 1$.

TABLE 2 SOLUTIONS FOR THE VARIOUS CHARACTERISTIC FREQUENCIES

(Clause 3.3.3)

CHARACTERISTIC FREQUENCY	MEANING	CONDITION	CONSTITUENT EQUATION FOR FREQUENCY	ROOT
(1)	(2)	(3)	(4)	(5)
f_m	Frequency of maximum admittance (minimum impedance)	$\frac{d Z }{d\omega} = 0$	$(\Omega^2 + \delta^2)^2 - 2\delta^2(\Omega + r) - 2\Omega r(1 - \Omega) - \Omega^2 = 0$	Lower*
f_s	Motional (series) resonance frequency	$X_1 = 0$	$\Omega = 0$	
f_r	Resonance frequency	$X_e = B_p = 0$	$\Omega(1 - \Omega) - \delta^2 = 0$	Lower
f_a	Antiresonance frequency	$X_e = B_p = 0$	$\Omega(1 - \Omega) - \delta^2 = 0$	Upper
f_p	Parallel resonance frequency (lossless)	$X_e \Big _{R_1=0} = \infty$	$\Omega = 1$	
f_n	Frequency of minimum admittance (maximum impedance)	$\frac{d Z }{d\omega} = 0$	$(\Omega^2 + \delta^2)^2 - 2\delta^2(\Omega + r) - 2\Omega r(1 - \Omega) - \Omega^2 = 0$	Upper*

*Refers to real roots; complex roots to be disregarded.

TABLE 3 MINIMUM VALUES FOR THE RATIO Q^2/r TO BE EXPECTED FOR VARIOUS TYPES OF PIEZOELECTRIC VIBRATORS

(Clause 3.3.5)

TYPE OF PIEZOELECTRIC VIBRATOR	$Q = Mr$	r	Q^2/r min
(1)	(2)	(3)	(4)
Piezoelectric ceramics	90-500	2-40	200
Water-soluble piezoelectric crystals	200-50 000	3-500	80
Quartz	10^4-10^7	100-50 000	2 000

TABLE 4 APPROXIMATE RELATIONS BETWEEN THE CHARACTERISTIC FREQUENCIES AND THE SERIES RESONANCE FREQUENCY f_s OF A PIEZOELECTRIC VIBRATOR

(Clause 3.3.8)

CHARACTERISTIC FREQUENCY	FIRST APPROXIMATION		SECOND APPROXIMATION	
	$\frac{f}{f_s}$	Deviation $\frac{\Delta f}{f_s}$ from more precise value	$\frac{f}{f_s}$	Deviation $\frac{\Delta f}{f_s}$ from more precise value
(1)	(2)	(3)	(4)	(5)
f_m	$\frac{f_m}{f_s} = 1$	$-\frac{1}{2M^2r}$	$\frac{f_m}{f_s} = \sqrt{1 + \frac{1}{2r} \left(1 - \sqrt{1 + \frac{4}{M^2}}\right)}$	$\frac{1}{2M^4r^2}$
f_r	$\frac{f_r}{f_s} = 1$	$\frac{1}{2M^2r}$	$\frac{f_r}{f_s} = \sqrt{1 + \frac{1}{2r} \left(1 - \sqrt{1 - \frac{4}{M^2}}\right)}$	$\frac{1}{2M^4r^2}$
f_a	$\frac{f_a}{f_s} = 1 + \frac{1}{2r}$	$-\frac{1}{2M^2r} \left(\frac{1}{r} + 1\right)$	$\frac{f_a}{f_s} = \sqrt{1 + \frac{1}{2r} \left(1 + \sqrt{1 - \frac{4}{M^2}}\right)}$	$-\frac{1}{2M^2r} \cdot \frac{1}{r}$
f_n	$\frac{f_n}{f_s} = 1 + \frac{1}{2r}$	$\frac{1}{2M^2r} \left(\frac{1}{r} + 1\right)$	$\frac{f_n}{f_s} = \sqrt{1 + \frac{1}{2r} \left(1 + \sqrt{1 + \frac{4}{M^2}}\right)}$	$\frac{1}{2M^2r} \cdot \frac{1}{r}$
f_p	$\frac{f_p}{f_s} = 1 + \frac{1}{2r}$	$-\frac{1}{8r^3}$	$\frac{f_p}{f_s} = \sqrt{1 + \frac{1}{r}}$	0

4.2 Transmission Measurement Circuit

4.2.1 Figure 4 shows a schematic representation of the transmission circuit. The measuring circuit consists of a constant current source in the form of a variable frequency oscillator, the transmission network and a voltmeter. The piezoelectric vibrator is represented by its equivalent electric circuit. The network is symmetrical with respect to the input and output. The capacitances C_T , which shunt the terminating resistances R_T , represent stray element which affect the accuracy of measurements as shown in Table 6. The oscillator shall have a high degree of purity of output waveform to an extent consistent with the requirements of the individual vibrator under test (see Note).

NOTE — For most practical purposes, the following requirements are adequate: harmonics greater than 30 dB below the main signal, frequency stability better than 1×10^{-6} and amplitude change less than 10 percent during the measurement period.

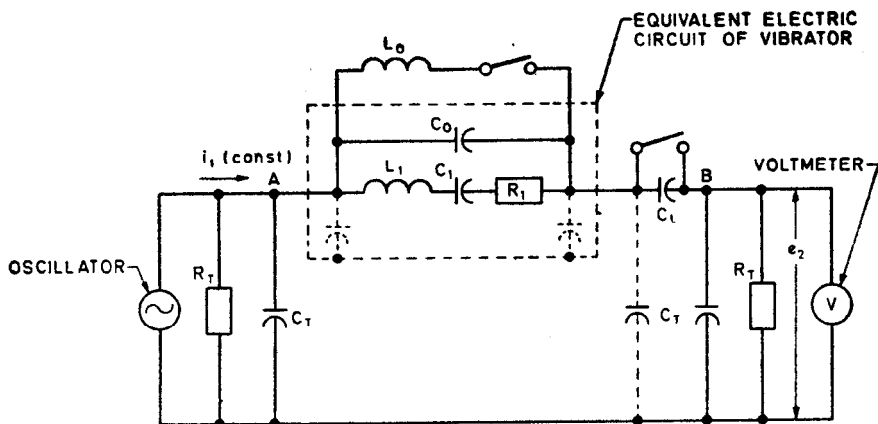


FIG. 4 SCHEMATIC DIAGRAM OF TRANSMISSION CIRCUIT METHOD

4.2.2 The inductance L_0 , connected across the vibrator, serves to resonate the shunt capacitance C_0 of the vibrator at f_s . This added component improves the accuracy of measurement as explained in 4.3.1.

4.2.3 An important source of stray capacitance to ground that shall be considered occurs at the junction of the crystal unit and the capacitor C_L (Fig. 4). This stray capacitance is composed of two parts: that associated with the crystal unit under test and that associated with C_L . When the magnitude of these stray reactances is large compared with the magnitude of the termination impedance, the distributed capacitance to ground of the crystal unit and the distributed capacitance to ground of C_L at the junction may be treated in a first approximation as being in parallel with C_L . While measuring the parameters of crystal units by other than the transmission method, consideration shall be given to the stray capacitance of each terminal of the crystal unit to ground. This is of course an important consideration in the use of crystal units in network and frequency control applications.

4.2.4 The voltmeter which is placed at the output, measures the voltage e_2 as the frequency of the input is varied.

4.3 Procedure for Measurement and Determination of the Parameters

4.3.1 Motional Resistance R_1 — The motional resistance is measured by adjusting the frequency of the oscillator to obtain maximum transmission (maximum e_2) of the vibrator. The resistor is adjusted to the particular value R_{st} for which the maximum transmission value e_2 is equal to the value obtained with the vibrator. The general relation between R_1 and R_{st} is given in equation (4) (see Table 6). Assuming that $C_T = 0$, R_1 can be calculated from equation (4b) (see Table 6). While substituting R_{st}

for R_1 and when compensating inductance L_0 is not used, the error in R_1 will be:

$$100 \cdot \left(\frac{R_{st}}{X_0} \right)^2 \left(\frac{4 R_T}{R_{st}} + 1 \right) \text{ percent} \quad \dots (5)$$

4.3.1.1 Proper adjustment of L_0 for $b = 0$ (see Table 5) reduces this error to zero [see equation (4f) in Table 6].

4.3.2 Motional Capacitance C_1 and Inductance L_1 — The motional capacitance C_1 is determined by measuring the frequency of maximum transmission f_{mT} using one or more load capacitances C_L (see Note) connected successively in series with the vibrator (see Fig. 4). When $M \gg 1$, which is usually the case, the readings obtained by use of two different load capacitances C_{L1} and C_{L2} can be combined so that:

$$C_1 = \frac{2 \Delta C_L}{f_s} \frac{\Delta f_1 \Delta f_2}{\Delta f} \quad \dots (6)$$

where

$$\left. \begin{aligned} \Delta C_L &= C_{L2} - C_{L1} \\ \Delta f &= f_{sL1} - f_{sL2} \\ \Delta f_1 &= f_{sL1} - f_s \\ \Delta f_2 &= f_{sL2} - f_s \end{aligned} \right\} \quad \dots (7)$$

and f_{sL1} and f_{sL2} are the motional resonance frequencies of the vibrator in series with C_{L1} and the vibrator in series with C_{L2} respectively. The frequencies of maximum transmission may be used in equation (7) instead of the respective motional resonance frequencies resulting in an error in C_1 of less than 3 percent for $(Q^2/r) \geq 80$. To obtain higher accuracy, the motional resonance frequencies have to be calculated from the frequencies of maximum transmission according to 4.3.3 and Table 6. As the equations in Table 6 are based on the equivalent electric circuit shown in Fig. 1, equations (8) have to be used to obtain the corresponding parameters for the combination of vibrator plus C_L . When a capacitance C_L is in series with an electroded element, the diagram shown in Fig. 5 applies. The two circuits are equivalent having the following relationships:

$$\left. \begin{aligned} L'_1 &= L_1 \left(1 + \frac{C_0}{C_L} \right)^2 \\ C'_1 &= C_1 \frac{1}{\left(1 + \frac{C_0}{C_L} \right)^2 \left(1 + \frac{C_1}{C_0 + C_L} \right)} \\ R'_1 &= R_1 \left(1 + \frac{C_0}{C_L} \right)^2 \\ C'_0 &= \left(\frac{C_0 C_L}{C_0 + C_L} \right) \end{aligned} \right\} \quad \dots (8)$$

NOTE — See 4.2 for the effect of stray capacitance on C_L .

4.3.2.1 When the frequencies of maximum transmission are measured using different values for C_L , it is important to maintain the current through the vibrator constant to within 10 percent as indicated by the voltmeter.

4.3.2.2 The inductance L_1 follows from:

$$L_1 = (\omega_s^2 C_1)^{-1} \quad \dots (9)$$

when the values for ω_s^2 and C_1 are known.

4.3.3 Motional Resonance Frequency f_s — The frequency of the oscillator is adjusted for maximum transmission with the piezoelectric vibrator inserted in the network shown in Fig. 4. This is the frequency of maximum transmission f_{mT} . At the first approximation, f_{mT} is equal to the frequency of minimum impedance f_m and the motional resonance frequency f_s of the vibrator. If higher accuracy for f_s is required, Table 6 should be consulted which gives the relationship between f_{mT} and f_s as the ratio:

$$\frac{f_{mT}^2}{f_s^2} - 1$$

for different degrees of approximation as a function of the network parameters. When the shunting inductance L_0 is omitted, equation (10b) in Table 6 becomes

$$\frac{f_{mT}^2}{f_s^2} - 1 = \frac{1}{r} \left[1 + \frac{2}{M^2 \left(1 + \frac{4 R_T}{M^2 R_1} \right) \left\{ 1 - \sqrt{1 + \frac{4}{M^2 \left(1 + \frac{4 R_T}{M^2 R_1} \right)^2}} \right\}} \right] \quad \dots (11a)$$

4.3.3.1 When $M^2 \gg 1$ is fulfilled for the resonator, the general formula 10 reduces to:

$$\frac{f_{mT}^2}{f_s^2} - 1 \approx \frac{-1}{M^2 r} \left(\frac{4 R_T}{R_1} + 1 \right) \quad \dots (11b)$$

and since the right-hand side of equation (11b) is usually much smaller than unity, it further reduces to:

$$\frac{f_{mT} - f_s}{f_s} = \frac{\Delta f}{f_s} \approx \frac{-1}{2 M^2 r} \left(\frac{4 R_T}{R_1} + 1 \right) \quad \dots (11c)$$

4.3.3.2 In most instances, $M^2 \gg 1$, and the approximate equation (11c) is satisfactory. When this condition is not fulfilled, the exact formula (11a) shall be used.

4.3.4 Network Requirements

4.3.4.1 The accuracy of the results increases as the following conditions

are fulfilled:

- Stray capacitance C_{A-B} between terminals A and B is low compared to vibrator capacitance C_0 ($C_0 \gg C_{A-B}$).
- Reactance of stray capacitance C_{A-B} is high compared to series resistance R_1 ($|X_{A-B}| \gg R_1$).
- The reactance of leads connecting vibrator is low compared to reactance of C_0 .

4.3.4.2 In the case of vibrators with low figure of merit M , it is advisable to use a shunting coil L_0 connected in parallel with the vibrator. If the combination $L_0 C_0$ is tuned to the motional resonance frequency f_s of the vibrator, $b=0$ and the measurement is simplified. In Table 6, equations (4a) and (10a) supply resistance and frequency values for this condition. It is seen that when $b=0$ and $M_T \gg 1$ [condition (a) in 4.3.4.1], then $f_{mT}=f_s$ and $R_{st}=R_1$.

4.3.5 Shunt Capacitance C_0

4.3.5.1 The shunt capacitance C_0 of the equivalent electric circuit of a vibrator is slightly smaller than the measured value for a free piezoelectric element and slightly greater than the measured value for a piezoelectric element in clamped condition. The exact value of the dielectric permittivity depends upon the mode of vibration. This has to be considered when greater accuracy is required.

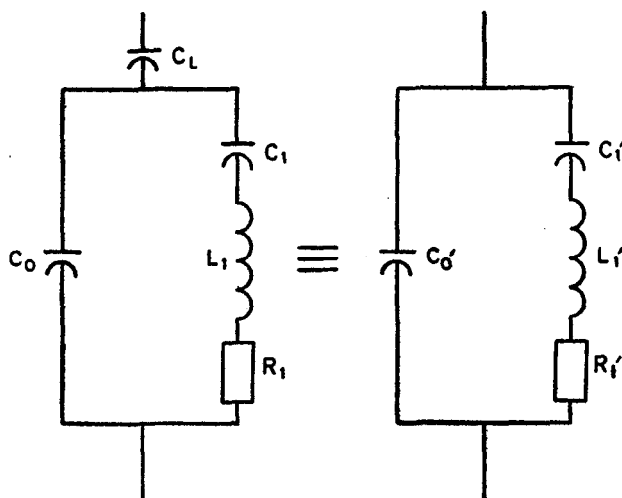


FIG. 5 EQUIVALENT ELECTRIC CIRCUIT OF A PIEZOELECTRIC VIBRATOR WITH A SERIES (LOAD) CAPACITANCE C_L

TABLE 5 LIST OF SYMBOLS USED IN TRANSMISSION NETWORK

(Clauses 4.1.2 and 4.3.1.1)

SYMBOL	MEANING	SI UNIT
b	Normalized compensation factor: $1 - \frac{1}{4 \pi^2 f_s^2 C_0 L_0}$	dimensionless
B	Normalized admittance factor	dimensionless
C	Normalized admittance factor	dimensionless
C_{A-B}	Stray capacitance between the terminals A-B (Fig. 4)	farad
C_L	Load capacitance	farad
C_T	Shunt capacitance terminating transmission circuit	farad
C_{L1}	Load capacitance	farad
C_{L2}	Load capacitance	farad
e_s	Output voltage of transmission network	volt
f_{mT}	Frequency of maximum transmission	hertz
f_{sL1}	Motional resonance frequency of combination of vibrator and C_{L1}	hertz
f_{sL2}	Motional resonance frequency of combination of vibrator and C_{L2}	hertz
i_1	Input current to transmission network	ampere
L_0	Compensation inductance shunting vibrator	henry
M_T	Figure of merit of transmission network termination: $M_T = \frac{1}{2 \pi f_s C_T R_T} = \frac{X_T}{R_T}$	dimensionless
R_T	Shunt resistance termination of transmission network	ohm
R_{st}	Standard resistor	ohm
S	Detector sensitivity (smallest detectable current change/current)	dimensionless
x	Normalized frequency factor: $x = \frac{f^2}{f_s^2} - 1 = \frac{\Omega}{r}$	dimensionless
X_{A-B}	Reactance of stray capacitance C_{A-B}	ohm
X_T	Reactance of C_T at the motional resonance frequency: $X_T = \frac{1}{2 \pi f_s C_T}$	ohm
x_{mT}	Normalized frequency factor at the frequency of maximum transmission	dimensionless
ΔC_L	$\Delta C_L = C_{L2} - C_{L1}$	farad
Δf	$\Delta f = f_{sL1} - f_{sL2}$	hertz
Δf_1	$\Delta f_1 = f_{sL1} - f_s$	hertz
Δf_2	$\Delta f_2 = f_{sL2} - f_s$	hertz

TABLE 6 RELATIONSHIP BETWEEN MEASURED AND FUNDAMENTAL VALUES

(Clauses 4.1.3, 4.2.1, 4.3.1, 4.3.1.1, 4.3.2, 4.3.3, 4.3.4.2 and 4.4.3)

	$R_1 =$	$\frac{f_{mT}^2}{f_s^2} - 1 =$
Complete solution	$\frac{R_T (2 - \nu)}{\frac{C_0^2 b^2 \nu^2}{C_T^2 (1 + M_T^2)} - \frac{4 b C_0}{M_T^2 C_T} \left(b \frac{C_0}{C_T} + 1 \right) - \left(1 + \frac{1}{M_T^2} \right)} \quad \dots (4)$ <p>where</p> $\nu = \sqrt{\left\{ 2 + \frac{R_{st}}{R_T} \left(1 + \frac{1}{M_T^2} \right) \right\}^2 + \frac{4}{M_T^2}}$	$\frac{1}{r b} + \frac{\frac{b}{r M^2} \left(1 + C + \frac{2}{M_T^2} \right)}{B - 1 + \left(1 + \frac{1}{M_T^2} \right)}$ $\left[1 - \sqrt{\frac{1}{1 + \frac{1}{M_T^2}} \left\{ B^2 + \frac{4 b^2}{M^2} C + \frac{1}{M_T^2} \left(1 + \frac{4 b^2}{M^2} \right) \right\}} \right] \quad \dots (10)$ <p>where</p> $B = 1 + \frac{4 b^2}{M^2} \frac{R_T}{R_1}$ $C = 1 + \frac{4 b}{M M_T} \frac{R_T}{R_1}$
$b = 0$	$\frac{R_T \left[\sqrt{\left\{ 2 + \frac{R_{st}}{R_T} \left(1 + \frac{1}{M_T^2} \right) \right\}^2 + \frac{4}{M_T^2}} - 2 \right]}{1 + \frac{1}{M_T^2}} \quad \dots (4a)$	$\frac{2 R_T}{r M M_T R_1 \left(1 + \frac{1}{M_T^2} \right)} \quad \dots (10a)$
$C_T = 0$	$\frac{R_{st}}{1 - \frac{R_{st}^2}{X_0^2} b^2 \left(4 \frac{R_T}{R_{st}} + 1 \right)} \quad \dots (4b)$	$\frac{1}{r b} + \frac{2 b}{r M^2 B \left(1 - \sqrt{1 + \frac{4 b^2}{M^2 B^2}} \right)} \quad \dots (10b)$

	$R_1 =$	$\frac{f_{\text{m}\pi}^2}{f_s^2} - 1 =$
$R_T = \infty$	$\frac{R_{\text{st}} \sqrt{1 + \left(\frac{2X_T}{R_{\text{st}}}\right)^2}}{1 + 4b \frac{C_0}{C_T} - \frac{R_{\text{st}}^2}{X_0^2} b^2} \quad \dots (4c)$	$\frac{1}{rb} + \frac{2b \left(2b \frac{C_0}{C_T} + 1\right)}{r M^2 \left\{1 - \sqrt{\frac{4b^2}{M^2} \left(1 + 2b \frac{C_0}{C_T}\right)^2 + 1}\right\}} \quad \dots (10c)$
$\frac{4}{M_T^2} \ll 1$	$\frac{R_{\text{st}}}{1 + \frac{4b}{M_T^2} \frac{C_0}{C_T} - \frac{b^2}{M_T^2} \left(\frac{R_{\text{st}}}{R_T} \frac{C_0}{C_T}\right)^2 \left(1 + 4 \frac{R_T}{R_{\text{st}}}\right)} \quad \dots (4d)$	$\frac{2}{M^2 r} \frac{C_T}{C_0} \frac{R_T^2}{R_1^2} - \frac{4b}{M^2} \frac{R_T}{R_1 r} - \frac{b}{M^2 r}$ is valid for $b^2/M^2 \ll 1$ $\dots (10d)$
$b = 0;$ $R_T = \infty$	$R_{\text{st}} \sqrt{1 + \left(\frac{2X_T}{R_{\text{st}}}\right)^2} \quad \dots (4e)$	$2 \frac{C_1}{C_T} \quad \dots (10e)$
$b = 0$ $C_T = 0$	$R_{\text{st}} \quad \dots (4f)$	$0 \quad \dots (10f)$

4.3.5.2 There is no direct method for measuring C_0 precisely. However, in nearly all practical cases it is adequate to regard as C_0 the mean value of the shunt capacitances C_{01} and C_{02} of the resonator obtained at two frequencies, equidistant above and below the resonance frequency and sufficiently removed from the latter for the impedance to be independent of any response. C_{01} and C_{02} can be measured by means of an impedance bridge or a Q-meter.

4.3.5.3 It should be noted that C_0 is the shunt capacitance between the two electrodes of the resonator. As pointed out in 4.2, the capacitances of both of the electrodes to ground are important elements in many network and frequency control applications. Proper use of the transmission circuit method for the measurement of C_1 requires knowledge of at least the capacitance to ground of that electrode of the resonator which is connected to C_L (see Fig. 4).

4.3.5.4 Therefore, in the general case, it is necessary to consider the crystal unit as a three-terminal network and to evaluate C_0 and the stray capacitances of the two electrodes to ground from open- and short-circuit measurements according to the techniques customarily employed when dealing with two-port devices.

4.3.5.5 The crystal enclosure remains at ground potential during the entire series of measurements required for evaluation of the resonator parameters. For this purpose, it may be found desirable to provide glass-enclosed crystal units with metal shells.

4.4 Numerical Examples

4.4.1 The mean deviation of f_s from its true values, due to detector sensitivity S alone, is given by:

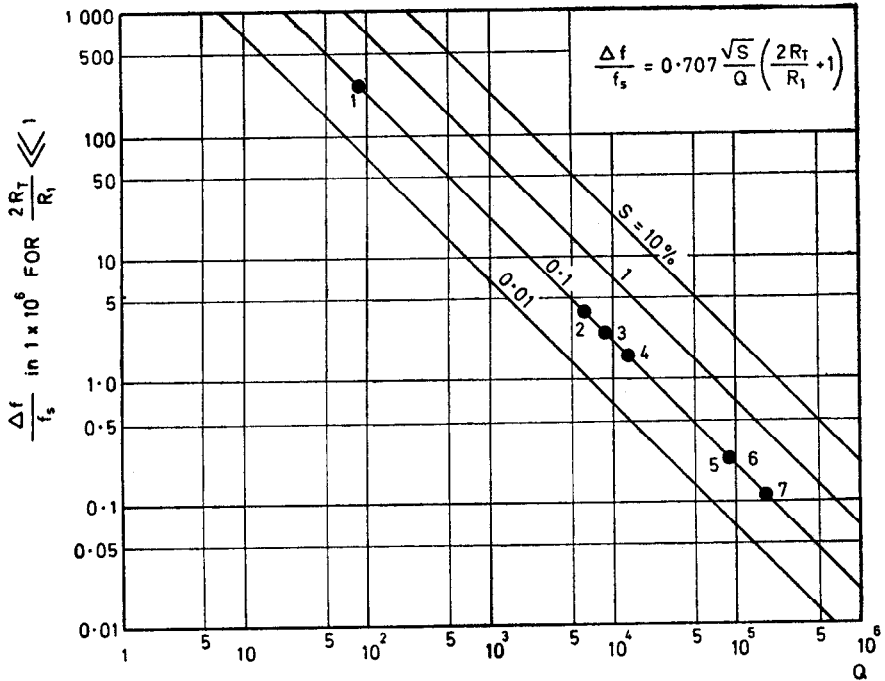
$$x \approx \frac{\Delta f}{f_s} = \frac{1}{\sqrt{2}} \left(\frac{2 R_T}{R_1} + 1 \right) \frac{\sqrt{S}}{Q} \quad \dots \quad (12)$$

4.4.2 This equation is valid if $4/M_T^2 \ll 1$ and $b^2/M^2 \ll 1$. The magnitude of the mean deviation is plotted in Fig. 6 for various values of S as a function of Q .

4.4.3 The equations in Table 6 give the corrections necessary to obtain R_1 from R_{st} and f_s from f_{mT} respectively in terms of the vibrator and network parameters. When the assumptions leading to the simplified relations [equations (5) and (11c)] are met, the magnitude of these corrections can be obtained from the graphs shown in Fig. 7 and 8.

4.4.4 The solid lines in these graphs further assume that $2 (R_T/R_1) \ll 1$ (Fig. 6), $\frac{4(R_T)}{R_{st}} \ll 1$ (Fig. 7), and $\frac{4(R_T)}{R_1} \ll 1$ (Fig. 8). The ordinate values

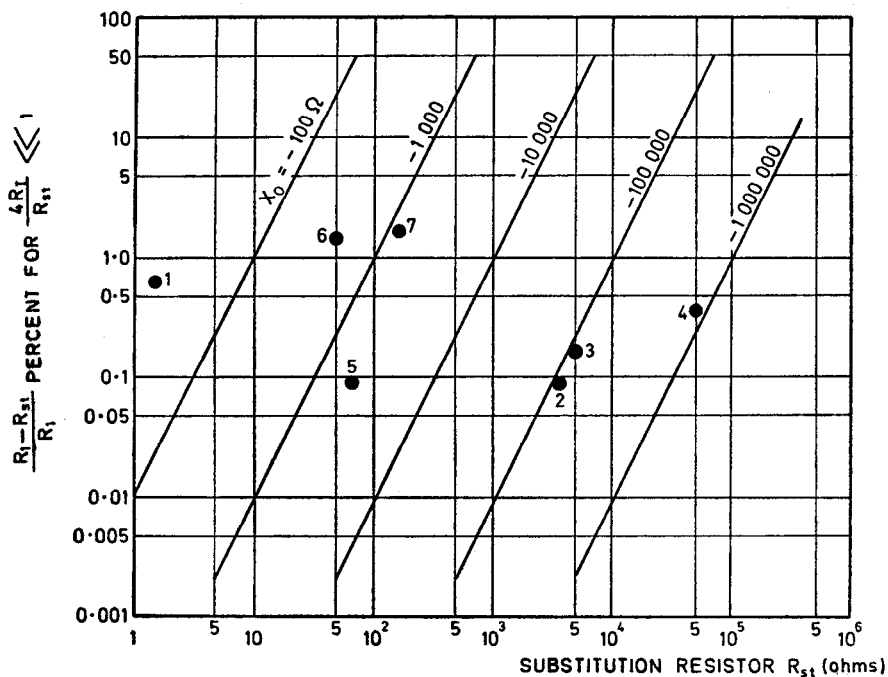
of the graphs (Fig. 6 to 8) can be modified easily when these relationships are not fulfilled. The examples shown in the graphs refer to the vibrators listed in Fig. 6 and illustrate that R_1 generally differs from R_{st} by less than 2 percent (Fig. 7) and that, excluding ceramics, the differences between f_s and f_{mT} are of the order 1×10^{-6} (Fig. 8). Shunt coils were not used for these measurements.



Examples:

1. Barium titanate longitudinal mode
2. Quartz CT element 300 kHz
3. Quartz DT element 300 kHz
4. Quartz NT element 100 kHz
5. Quartz AT 3rd overtone 15 MHz
6. Quartz AT 5th overtone 70 MHz
7. Quartz AT 5th overtone 23.3 MHz

FIG. 6 MEAN DEVIATION $\frac{\Delta f}{f_s}$ DUE TO VOLTMETER SENSITIVITY S

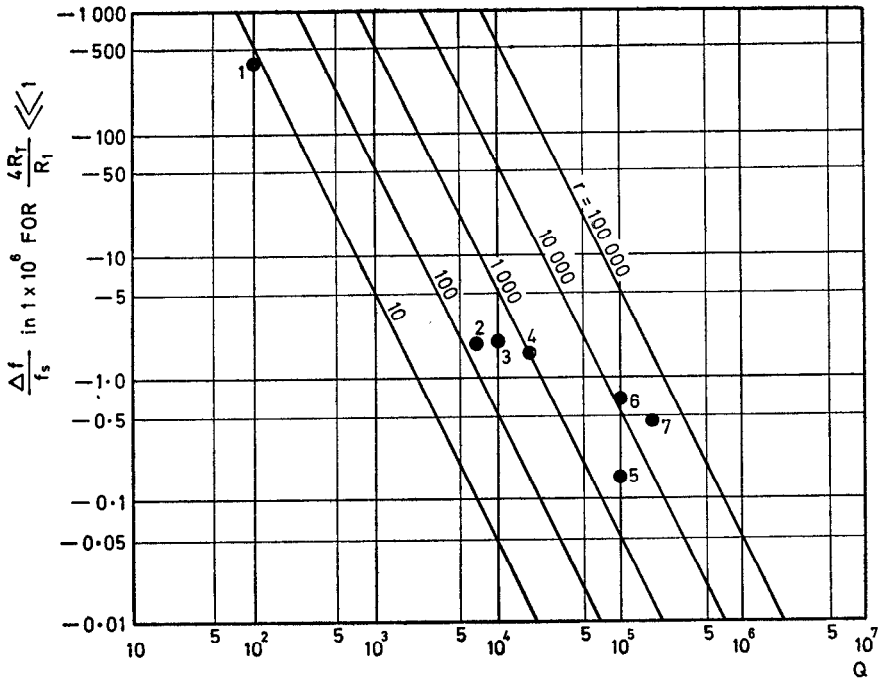


Examples :

1. Barium titanate longitudinal mode
2. Quartz CT element 300 kHz
3. Quartz DT element 300 kHz
4. Quartz NT element 100 kHz
5. Quartz AT 3rd overtone 15 MHz
6. Quartz AT 5th overtone 70 MHz
7. Quartz AT 5th overtone 23.3 MHz

NOTE : $1 - \frac{R_{st}}{R_1} = \left(\frac{R_{st}}{X_0} \right)^2 \left(\frac{4 R_T}{R_{st}} + 1 \right)$

FIG. 7 RESISTANCE MEAN DEVIATION



Examples :

1. Barium titanate longitudinal mode
2. Quartz CT element 300 kHz
3. Quartz DT element 300 kHz
4. Quartz NT element 100 kHz
5. Quartz AT 3rd overtone 15 MHz
6. Quartz AT 5th overtone 70 MHz
7. Quartz AT 5th overtone 23.3 MHz

NOTE : $\frac{\Delta f}{f_s} = - \frac{r}{2Q^2} \left(1 + \frac{4R_T}{R_1} \right)$

FIG. 8 MEAN DEVIATION $\frac{\Delta f}{f_s}$ DUE TO VIBRATOR AND CIRCUIT PARAMETERS

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